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New Online at https://aerobasegroup.com/hsil/3901-01-150-9731
Inclosure Material:
Metal
Overall Length:
2.870 inches
Overall Height:
1.032 inches
Overall Width:
2.350 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-200ac
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Compression
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
10.0 peak gate voltage
Current Rating Per Characteristic:
50.00 amperes forward current, total rms megawatts
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnpnp
Terminal Type And Quantity:
2 ferrule and 1 turret and 1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0